

RESEARCH ARTICLE

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2020, 4, 1648Highly efficient exciplex-based OLEDs
incorporating a novel electron donor†Qi-Sheng Tian,^a Xiang-Dong Zhu^a and Liang-Sheng Liao^{id} *^{ab}

A novel triphenylamine (TPA) derivative molecule 4,4,8,8,12,12-hexaphenyl-8,12-dihydro-4*H*-benzo[9,1]-quinolino[3,4,5,6,7-*defg*]acridine (**DEX**) is presented as an electron donor to form an effective exciplex system with an electron acceptor molecule ((1,3,5-triazine-2,4,6-triyl)tris(benzene-3,1-diyl))tris(diphenylphosphine oxide) (**PO-T2T**) for fabricating high performance exciplex-based organic light-emitting diodes (OLEDs). If the **DEX:PO-T2T** exciplex itself is used as an emitting layer without any doped luminescent emitter in an OLED, it can exhibit green emission with a maximum power efficiency (PE_{\max}), current efficiency (CE_{\max}), and external quantum efficiency (EQE_{\max}) of 44.6 lm W⁻¹, 36.0 cd A⁻¹, and 11.2%, respectively. The high device performance indicates that the green exciplex would have balanced charge transport properties, a broad recombination zone, and a suitable triplet energy level (E_T), which is therefore expected to serve as an ideal host for a red phosphorescent emitter. Indeed, due to the desirable thermal and electrical properties of donor **DEX**, an optimized exciplex-based red phosphorescent OLED (PhOLED), doped with iridium(III) bis(2-methylidibenzof[*h*,*h'*]quinoxaline)acetylacetonate (**Ir(MDQ)₂(acac)**), achieved an impressive PE_{\max} , CE_{\max} , and EQE_{\max} of 46.1 lm W⁻¹, 36.0 cd A⁻¹, and 24.5% as well as a low operating voltage (2.4 V at 0.2 mA cm⁻²). Remarkably, both an excellent EQE over 22% and low operating voltage of 3.4 V remained even at a high brightness of 1000 cd m⁻². The high EQE and low efficiency roll-off reveal that the new exciplex system using novel donor **DEX** enables improved OLED performance, which paves the way to practical applications of OLEDs.

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Introduction

Organic light-emitting diodes (OLEDs) have opened a reliable avenue in optoelectronic devices due to their inherent characteristics, such as high-contrast, high-efficiency, and flexibility.^{1–3} The development of conventional fluorescent material-based OLEDs is impeded by the limited internal quantum efficiency (IQE) of 25% without being capable of utilization of the remaining 75% nonradiative triplet excitons.⁴ Over the past decades, 2nd generation OLEDs employing phosphorescent emitters have offered striking EQE *via* harvesting both singlet and triplet excitons for 100% internal quantum efficiency (IQE).^{5–7} Recently, thermally activated delayed fluorescence (TADF) materials commonly exhibit typical intramolecule charge transfer (ICT) behavior, which show an effective reverse intersystem crossing (RISC) process and small singlet–triplet energy splitting (ΔE_{ST}).^{8–10} So, they have the ability to efficiently

utilize both singlet and triplet excitons by converting triplet excitons from the triplet excited state (T_1) into the singlet excited state (S_1). Thereby, phosphorescent and TADF materials are widely considered as promising strategies to sufficiently utilize excitons for achieving high performance devices.

Exciplex systems comprising an electron donor and an electron acceptor can contribute to intermolecular charge transfer accompanied by effective RISC and a small ΔE_{ST} .^{11–13} So the exciplex is considered as another type of efficient TADF emitter to fabricate high-efficiency exciplex-based fluorescent OLEDs.^{13,14} It's worth noting that an exciplex is generally a combination of an electron-transporting material and a hole-transporting material, which can realize balanced charge transport, a negligible injection barrier, and a broad recombination zone. Therefore, several exciplex forming hosts have been developed and they played a crucial role to reduce the operating voltage in devices for enhancing the power efficiency (PE).^{15–17} Ideally, an exciplex system can be not only regarded as the emitting layer to fabricate efficient fluorescent OLEDs, but also serve as a co-host to enhance the performance of emitters. Thus, designing an effective exciplex system is in demand for the development of OLEDs.

However, it is relatively rare to select an electron donor for fabricating an exciplex system in order to achieve high

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performance OLEDs, because most researchers pay more attention to designing electron acceptor materials, *e.g.*, star-shaped 1,3,5-triazine/cyano hybrid molecule CN-T2T,¹⁸ heptazine derivative HAP-3MF,¹³ benzimidazole-triazine-based electron acceptor PIM-TRZ,¹⁹ and isomeric N-linked benzoimidazole materials (iTPyBIB, iTPBIPy, and iTPyBIPy).²⁰ These electron acceptor materials have shown significant roles in highly efficient exciplex systems. In contrast, the common electron donors widely utilized in exciplex systems are mainly restricted to commercial materials, such as 1,3-di-9-carbazolylbenzene (mCP),¹⁵ 1,1-bis[4-[*N,N'*-di(*p*-tolyl)amino]-phenyl]cyclohexane (TAPC),¹⁷ 4,4',4''-tris[3-methylphenyl(phenyl)amino] triphenylamine (*m*-MTDATA),¹¹ and *N,N,N*-tris(4-(9-carbazolyl)phenyl)amine (TCTA).²¹ It is therefore necessary to develop more appropriate electron donor materials to match suitable electron acceptor materials in fabricating effective exciplex systems for obtaining high performance OLEDs with high EQE and PE, and low operating voltage. With the expectation to design ideal electron donor materials, the following prerequisites should be mentioned: (i) obtaining a suitable E_T of the donor for ensuring effective energy transfer; (ii) achieving satisfactory highest occupied molecular orbital (HOMO) and lowest unoccupied molecular orbital (LUMO) levels to match well with the acceptor material and the adjacent charge transport materials for ensuring the formation of an exciplex; and (iii) realizing low cost, an uncomplicated synthesis procedure, and good thermal properties.

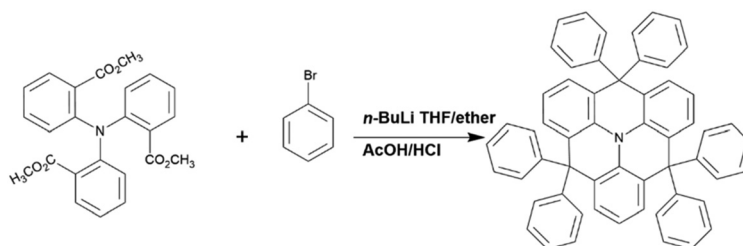
Reported herein is a new triphenylamine (TPA) derivative-based electron donor molecule 4,4,8,8,12,12-hexaphenyl-8,12-dihydro-4*H*-benzo[9,1]quinolizino[3,4,5,6,7-*defg*]acridine (DEX) that shows a desirable triplet energy level ($E_T = 2.75$ eV), good thermal stability, a facile synthetic process, and appropriate HOMO and LUMO levels. The electron donor DEX and an electron-transporting molecule ((1,3,5-triazine-2,4,6-triyl)tris(benzene-3,1-diyl))tris(diphenylphosphine oxide) (PO-T2T) were selected to fabricate a suitable exciplex system. An exciplex-based fluorescent OLED was first proposed and it can exhibit green emission peaking at 520 nm. Importantly, the green exciplex-based OLED can realize a maximum EQE (EQE_{max}) and PE (PE_{max}) and low operating voltage (at 0.2 mA cm⁻²) of 11.2%, 48.1 lm W⁻¹ and 2.5 V, respectively, which are superior to those of traditional fluorescent OLEDs. Furthermore, the green emission exciplex was proved as a promising co-host in devices to reduce the operating voltage and to broaden the exciton recombination zone for improving the performance of

red phosphorescent emitters, such as iridium(III) bis(2-methyl-dibenzo[*f,h*]quinoxaline)acetylacetonate Ir(MDQ)₂(acac). Finally, benefiting from the exciplex forming co-host, the optimized red phosphorescent OLED (PhOLED) with Ir(MDQ)₂(acac) as the emitter shows remarkable performance with an EQE_{max}, PE_{max}, and operating voltage (at 0.2 mA cm⁻²) of 24.5%, 46.1 lm W⁻¹ and 2.4 V, respectively. These superior results of the efficient green and red exciplex-based OLEDs can be ascribed to the properties of DEX, which has a suitable E_T , good photophysical characteristics, better carrier transport capability, and suitable frontier molecular orbitals (FOMs) as well as a reasonable device structure to facilitate charge injection and recombination.

Results and discussion

The synthetic route and chemical structure of the donor DEX are outlined in Scheme 1. The specific steps of the synthetic process are expressed in the Experimental section. It clearly shows that the synthetic process is particularly uncomplicated and convenient, proving that it has the practical potential for fabrication and applications. For investigating the electronic structure of DEX, density functional theory (DFT) calculations were applied at the B3LYP/6-31G(d) level. The HOMO/LUMO FMO distributions and energy levels are depicted in Fig. 1. The HOMO energy level (−5.03 eV) and LUMO energy level (−2.03 eV) of DEX can be calculated. From the ground state geometry, a singlet energy level (E_S) and E_T of 3.1 and 2.6 eV can be found, respectively.

To explore the electrochemical properties of DEX, the HOMO energy level was estimated through ultraviolet photo-spectroscopy (UPS) measurements (Fig. 2a). The UV-vis absorption and photoluminescence (PL) spectra of DEX in dilute CH₂Cl₂ solution at room temperature are shown in Fig. 2b. From the UPS curves we can conclude that DEX has a HOMO energy level of −5.8 eV, which is helpful to transfer holes.²² The maximum absorption at a wavelength around 300 nm is ascribed mainly to the π - π^* intramolecular transition. The onset of the UV-vis absorption edge of DEX is at about 344 nm, so the optical bandgap (E_g) can be estimated to be 3.6 eV. Hence, the LUMO energy level of DEX can be calculated according to the equation $E_g = -(E_{\text{HOMO}} - E_{\text{LUMO}})$ as *ca.* −2.2 eV. Meanwhile, the electrochemical properties of DEX were investigated by cyclic voltammetry (CV); from the reversible oxidation curve we can conclude that DEX is electrochemically



Scheme 1 Synthetic route and chemical structure of DEX.

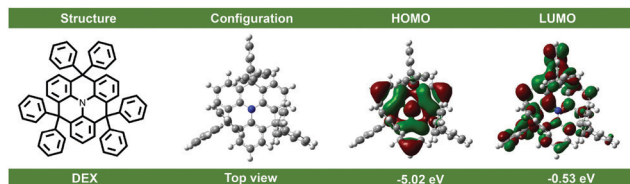


Fig. 1 Chemical structure, calculated molecular HOMO and LUMO distributions, and energy levels of **DEX**.

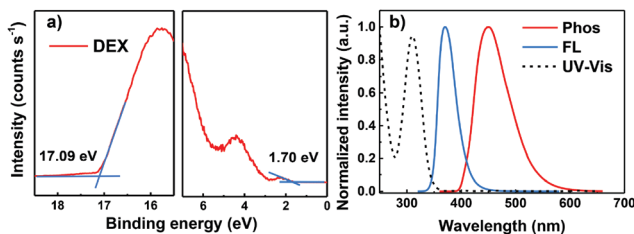


Fig. 2 (a) UPS spectrum of the **DEX** film, and (b) UV-vis absorption in CH_2Cl_2 and the fluorescence spectrum in toluene (300 K) as well as the phosphorescence (toluene, 77K) spectrum of **DEX**.

stable (shown in Fig. S4, ESI[†]). The wavelength of the peak emission of the phosphorescence spectrum at 77 K is 450 nm, indicating that the E_T of **DEX** is about 2.75 eV. The high T_1 level of **DEX** is beneficial to ensure energy transfer from the host to the emitters effectively.²³ The device performance is susceptible to the thermal properties of the organic material. As shown in Fig. S3 (ESI[†]), **DEX** exhibits distinguished thermal stability with a high decomposition temperature (T_d) of 397 °C (refers to 5% weight loss), which was calculated from thermogravimetric analysis (TGA). The high T_d indicates that **DEX** has excellent thermal properties, which is ascribed to its rigid molecular structure. The detailed photophysical properties are summarized in Table 1.

In order to fabricate an exciplex system with an effective intermolecular charge transfer process, a considerable offset (>0.4 eV) between the HOMO/LUMO energy levels of the donor/acceptor should be achieved.²⁴ Hence, an electron-transporting material **PO-T2T** was chosen to form an exciplex with **DEX** owing to its ideal HOMO/LUMO ($-3.5/-7.5$ eV) energy levels.¹⁵ Thus the energy level offset between **DEX** and **PO-T2T** is large enough to form an exciplex. The molecular configurations of **DEX** and **PO-T2T** are depicted in Fig. 3a. The exciplex forming process and energy level diagrams are illustrated in Fig. 3b.

Table 1 Summary of the photophysical properties of **DEX**

Molecule	Abs λ_{max}^a [nm]	PL λ_{max}^a [nm]	T_d^b [°C]	E_g^c [eV]	E_T^d [eV]	HOMO ^e [eV]	LUMO ^f [eV]
DEX	344	370	397	3.6	2.7	-5.8	-2.2

^a Tested in toluene solution at room temperature. ^b T_d : Decomposition temperature. ^c E_g : Optical band gap energy was measured from the corresponding absorption onset. ^d E_T : Measured in a toluene glass matrix at 77 K. ^e HOMO energy level was calculated from UPS data. ^f LUMO level was obtained from the results of the HOMO and E_g .

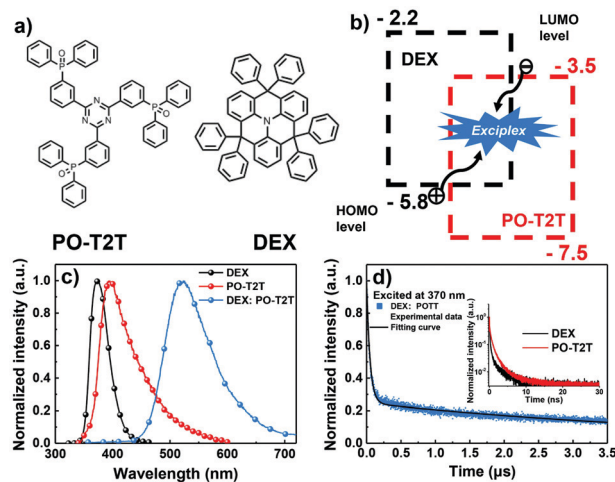


Fig. 3 (a) Molecular structures of **PO-T2T** and **DEX**, (b) the process of exciplex formation of **DEX:PO-T2T** with the HOMO and LUMO energy levels, (c) the PL spectra of **DEX**, **PO-T2T**, and **DEX:PO-T2T** films at 300 K, and (d) PL decay curves of exciplex **DEX:PO-T2T** and the pristine materials at 300 K.

To verify the formation of the **DEX:PO-T2T** exciplex, the PL spectrum of exciplex **DEX:PO-T2T** with peak emission at a wavelength of 520 nm was observed (shown in Fig. 3c). It is clearly found that the PL of the exciplex is red shifted compared with those of **DEX** (370 nm) and **PO-T2T** (410 nm), which means that an exciplex was generated.²⁵ The photo energy level of exciplex ($E_{S,\text{ex}}$) **DEX:PO-T2T** was experimentally measured to be 2.38 eV according to the PL peak emission (520 nm), which is consistent with the energy difference between the HOMO energy level (-5.8 eV) of **DEX** and the LUMO energy level (-3.5 eV) of **PO-T2T**.²³ The triplet energy level of the exciplex ($E_{T,\text{ex}}$) was estimated to be 2.3 eV based on previously reported exciplex-based work, which means that the exciplex system has a dramatically negligible ΔE_{ST} .^{26–28} These results demonstrate that electron–hole coupling was generated under external excitation. Additionally, the transient fluorescence decay curves of **DEX:PO-T2T** and the pristine molecules are shown in Fig. 3d. **DEX** and **PO-T2T** only exhibit decay lifetimes of a few nanoseconds. In contrast, prompt and delayed components could be observed in the **DEX:PO-T2T** transient decay curve. The exciplex exhibits a short and long decay lifetime of 30 ns and 1.2 μs , respectively. The aforementioned results reveal certain evidence that the formation of exciplex **DEX:PO-T2T** possessing small ΔE_{ST} with an effective RISC process is achieved.

To further study the potential advantages of the **DEX:PO-T2T** exciplex system, a **DEX:PO-T2T** exciplex-based OLED was first fabricated to investigate its electroluminescence (EL) properties. For better comparison, a classic hole-transporting material 4,4,4-tris(*N*-carbazolyl)triphenylamine (TCTA) ($E_T = 2.76$), which has HOMO and LUMO levels of -5.8 and -2.4 eV, respectively, was employed to fabricate an exciplex with **PO-T2T**.²⁹ As shown in Fig. S5 (ESI[†]), the exciplex TCTA:**PO-T2T** shows a broad spectrum with a wavelength of 520 nm, which is red shifted compared with TCTA (400 nm) and **PO-T2T**, indicating the

formation of an exciplex. The E_T values of exciplexes **DEX:PO-T2T** (2.3 eV) and **TCTA:PO-T2T** are very close according to their emission peaks (520 nm). The devices were designed with the structure of ITO/HAT-CN (10 nm)/TAPC (30 nm)/**DEX** or **TCTA** (10 nm)/**DEX:PO-T2T** or **TCTA:PO-T2T** (20 nm)/**PO-T2T** (45 nm)/Liq (2 nm)/Al (120 nm). Hexaaza-triphenylene hexacarbonitrile (**HAT-CN**) and lithium quinolate (Liq) were employed as hole and electron-injecting layers (HIL and EIL), respectively.²⁵ **TAPC** can serve as a hole-transporting layer (HTL) owing to its suitable HOMO energy level (−5.6 eV) and high E_T (2.98 eV),³⁰ which matches well with **DEX** and **TCTA**, so that the holes can smoothly transfer from the anode to the emission zone for generating excitons with electrons. The additional 10 nm **DEX** or **TCTA** was introduced as an electron-blocking layer to prevent the undesirable formation of exciplex **TAPC:PO-T2T**.³¹

The EL characteristics of the exciplex **DEX:PO-T2T** (Green₁) and **TCTA:PO-T2T** (Green₂) OLEDs are presented in Fig. 4. The exciplex-based OLEDs realized typical green emission with a peak at 520 nm, which is consistent with the PL one. So all excitons generated on **DEX:PO-T2T** and **TCTA:PO-T2T** are sufficiently used for the emission of the exciplex without energy loss. As the current density–voltage–luminance (J – V – L) curves show (Fig. 4a), low operating voltages of 2.6 and 3.5 V at a luminance of 100 and 1000 cd m^{-2} were achieved in Green₁. Notably, these values are lower than that of the **TCTA**-based OLED, indicating that **DEX** has better carrier transport properties compared with **TCTA**.³² The low operating voltages of both devices are due to the good injection and the direct recombination of holes from the HOMO of **DEX** or **TCTA** and electrons from the LUMO of **PO-T2T**. Because of the low operating voltages of the **DEX**-based device, an excellent PE_{max} and maximum CE (CE_{max}) of 44.1 lm W^{-1} and 36 cd A^{-1} were achieved. For the **TCTA**-based OLED, a PE_{max} and CE_{max} of 17.4 lm W^{-1} and 15.0 cd A^{-1} can be realized. Finally, the **DEX** and **TCTA**-based devices exhibited an EQE_{max} of 11.2% and 4.0%, respectively. The substantial difference in the performance between the two devices is mainly ascribed to the superior properties of **DEX**, having good carrier transport and

Table 2 Summary of the EL performance for green and red OLEDs

Devices ^a	V^b [V]	η_{CE}^c [cd A^{-1}]	η_{PE}^c [lm W^{-1}]	η_{ext}^c [%]	CIE ^d [x, y]
Green ₁	2.5	36.0, 18.2	44.1, 16.8	11.2, 5.8	0.29, 0.55
Green ₂	2.7	15.0, 14.3	17.5, 11.4	4.0, 3.8	0.29, 0.55
Red ₁	2.7	39.0, 31.5	45.3, 24.2	19.7, 16.0	0.54, 0.42
Red ₂	2.7	35.0, 31.0	40.8, 24.1	22.1, 19.6	0.60, 0.38
Red ₃	2.7	31.0, 29.2	36.2, 21.8	21.7, 20.4	0.62, 0.37
Red ₄	2.6	28.0, 26.4	33.3, 19.9	20.8, 19.6	0.63, 0.36
Red ₅	2.4	34.0, 30.5	44.2, 27.7	23.0, 20.9	0.62, 0.37
Red ₆	2.4	34.0, 31.2	43.7, 27.7	23.3, 21.3	0.62, 0.37
Red ₇	2.4	36.0, 33.1	46.1, 39.7	24.5, 22.4	0.62, 0.37
Red ₈	2.4	35.0, 31.3	45.2, 28.1	23.8, 21.4	0.62, 0.37

^a Devices in this work. ^b Voltages at 0.2 mA cm^{-2} . ^c Efficiencies of the maximum and at a brightness of 1000 cd m^{-2} . ^d CIE coordinates measured at 5 mA cm^{-2} .

a rigid molecular structure. Additionally, though they have the same HOMO levels, the LUMO level of **DEX** (−2.2 eV) is higher than that of **TCTA** (−2.4 eV), which means that electrons are blocked more effectively to recombine with holes for generating excitons and then emitting light in the **DEX** based exciplex system. Particularly, it should be mentioned that the high EQE of 11.2% is among the excellent efficiencies of exciplex-based OLEDs without any luminescent dopant (see Table S1, ESI†). The detailed EL performances of Green₁ and Green₂ are listed in Table 2.

The highly efficient **DEX:PO-T2T** exciplex system is expected to be employed as a co-host for improving the efficiencies of PhOLEDs. According to the above results of the **DEX:PO-T2T** exciplex system, we believe that the exciplex should act well as a host for red emitters. The energy-level diagram and chemical structures of each material in the exciplex-based red PhOLEDs are shown in Fig. 5a–c.^{33,34} Red PhOLEDs were fabricated with different electron-injection layers (EILs) corresponding to different emitting layers. The exciplex **DEX:PO-T2T** was first successfully used as a co-host for the red phosphorescent emitter **Ir(MDQ)₂(acac)**-based OLED with the configuration of ITO/HAT-CN (10 nm)/TAPC (30 nm)/**DEX** (10 nm)/**DEX:PO-T2T:Ir(MDQ)₂(acac)** (1 : 1, X wt%, X = 1, 3, 5, and 7, 20 nm)/**PO-T2T** (50 nm)/Liq (2 nm)/Al (120 nm); X = 1, 3, 5, and 7 correspond to the devices R₁, R₂, R₃, and R₄. Different doping ratios of the emitter were used to investigate the EL performance of the red devices. The EL characteristics of the red devices are shown in Fig. 6a–c. These devices show low onset voltages (at 0.2 mA cm^{-2}) and operating voltages (at 1000 cd m^{-2}) of 2.7 and 4.5 V, respectively (as shown in Fig. S6a, ESI†). As shown in Fig. 6c, the emission peak of **Ir(MDQ)₂(acac)** is red-shifted with the doping ratio increase, indicating the effect of intermolecular interactions and strong polarization.³⁵ At a low doping concentration of 1 wt%, the device Red₁ showed red emission peaking at 604 nm corresponding to Commission Internationale de l'Éclairage (CIE) coordinates of (0.54, 0.42). With increasing the doping concentration of the emitter, decreased intermolecular distances of the emitter will cause intense intermolecular interactions, and thereby red-shifted emission can be observed in devices Red₂–Red₄. Particularly, red emission with CIE coordinates of (0.63, 0.36) can be

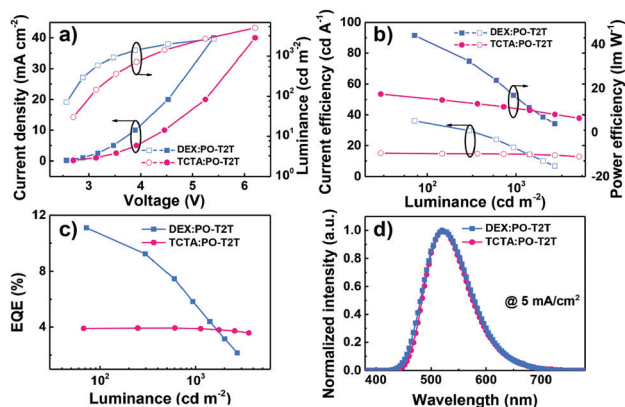


Fig. 4 (a) J – V – L plots, (b) CE –luminance– PE plots, (c) EQE –luminance plots, and (d) EL (at 5 mA cm^{-2}) spectra of **DEX:PO-T2T** and **TCTA:PO-T2T** exciplex-based devices.

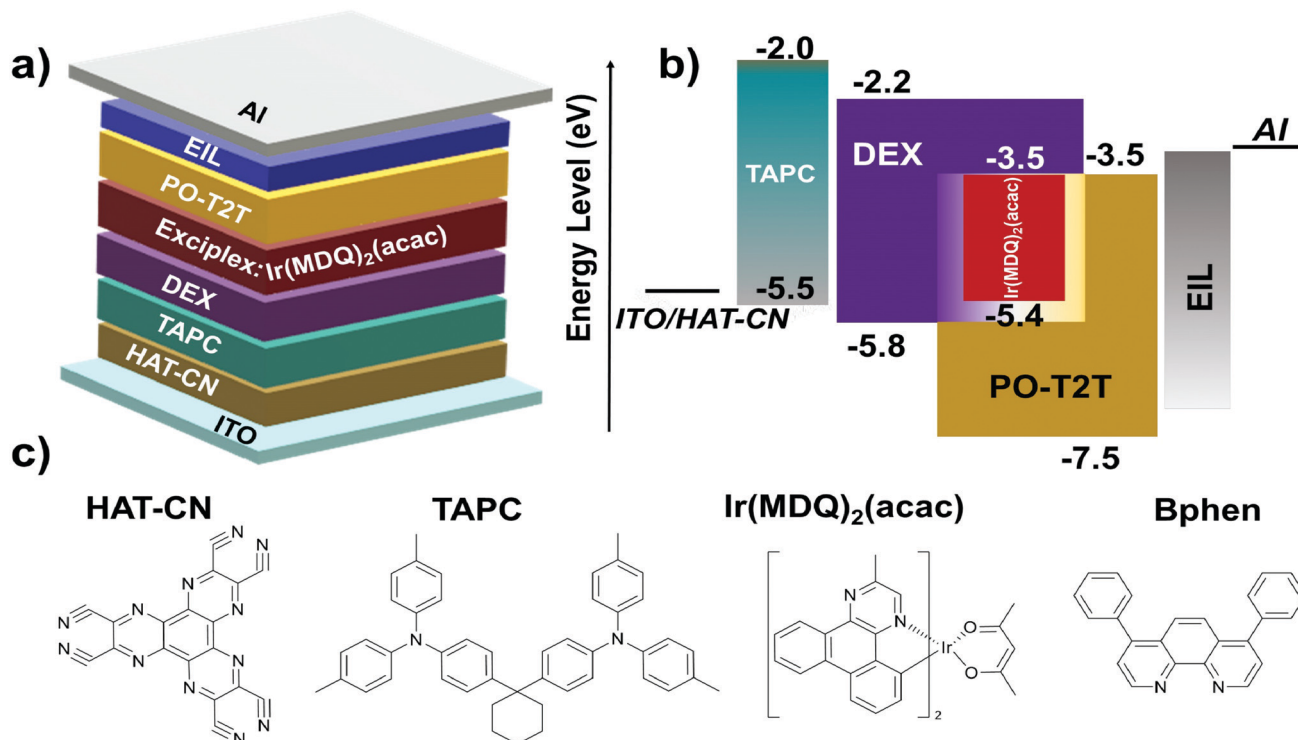


Fig. 5 (a) The optimized device structure of the red PhOLED, (b) energy-level diagram of the red PhOLED, and (c) chemical structures of the related materials in the red PhOLED.

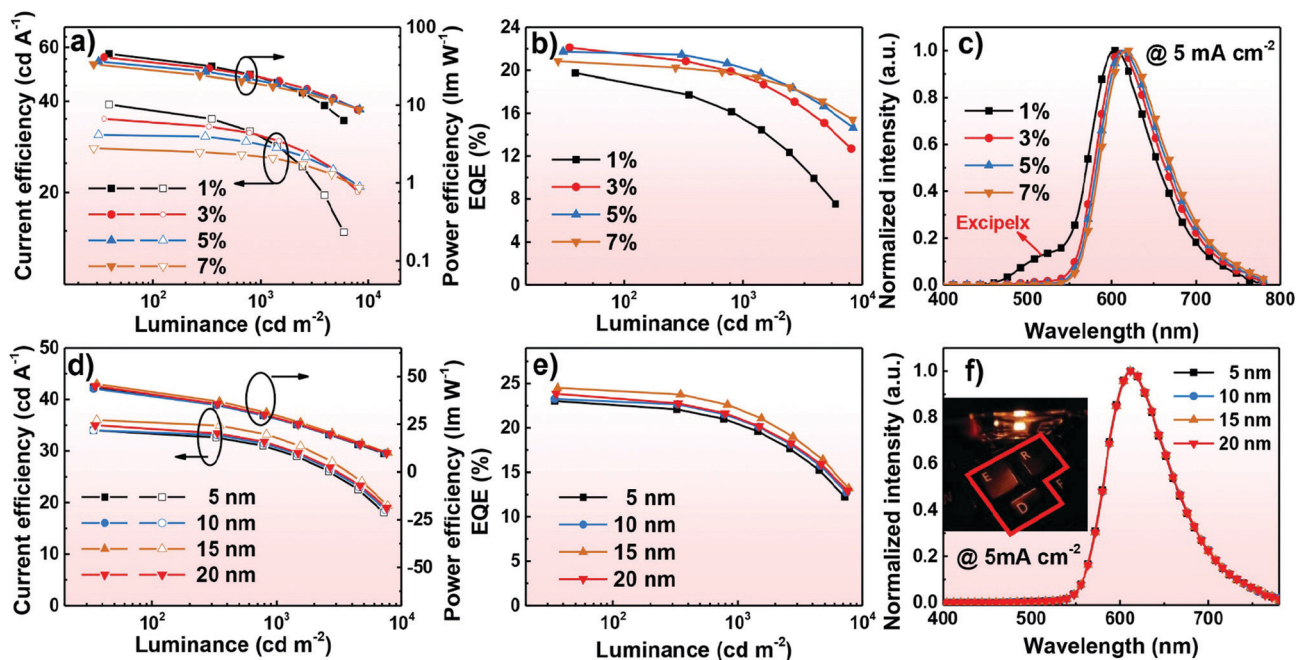


Fig. 6 (a) CE–luminance–PE plots, (b) EQE–luminance plots, and (c) EL spectra of the red OLEDs with different doping concentrations of emitters; (d) CE–luminance–PE, (e) EQE–luminance, and (f) EL spectra of the red OLEDs with LiH doped into the ETL and the inset graph is the red-emission of device R_7 at 5 mA cm^{-2} .

achieved in device Red_4 at a high doping concentration of 7 wt%. The detailed results of device R_1 – R_4 are summarized in Table 2. Notably, additional exciplex emission was observed

in the Red_1 device with a low doping ratio of 1 wt%, which illustrates that the undesirable phenomenon of inadequate energy transfer was generated.^{21,27,36} An EQE_{max} , CE_{max} , and

PE_{\max} of 19.7%, 39.0 cd A^{-1} , and 45.3 lm W^{-1} were presented in the Red₁ device with an emission peak of 604 nm. With the doping ratio changes, an excellent EQE_{\max} of 22.1%, 21.7%, and 20.8% was achieved for the R₂, R₃, and R₄ devices, and they can maintain high EQEs of about 20% at a high brightness of 1000 cd m^{-2} . The low efficiency roll-off is due to the sufficient utilization of excitons without energy loss and the broad recombination zone in the constructive exciplex forming co-host. It's worth noting that device R₃ (doping ratio of 5 wt%) can achieve desirable performance with CIE coordinates of (0.62, 0.37). The detailed characteristics of device R₁₋₄ are given in Table 2.

For further enhancing the efficiency of red OLEDs, n-doping technology was proposed in our devices. It is an effective method to enhance the electron injection and transport for decreasing the energy consumption.^{25,33} As a result, the LiH material with a 0.1 wt% doping ratio was doped into 4,7-diphenyl-1,10-phenanthroline (**Bphen**) to serve as an electron-injection layer. Hence, devices R₅₋₈ were fabricated with structures of ITO/HAT-CN (10 nm)/TAPC (30 nm)/DEX (10 nm)/DEX:PO-T2T:Ir(MDQ)₂(acac) (1:1, 5 wt%, 20 nm)/PO-T2T (*X* nm, *X* = 5, 10, 15, and 20)/Bphen: 0.1 wt% LiH (50-*X* nm)/Al (120 nm). We changed the thickness of PO-T2T to prevent the undesirable phenomenon where the lithium ions migrating into the emitting layer can seriously cause exciton quenching.³⁷ The emitter doping ratio was fixed at 5 wt%. From the *J-V-L* curves displayed in Fig. S6b (ESI[†]), the onset voltages of devices R₅₋₈ are approximately at 2.4 V and low operating voltages of 3.4 V can be realized at a high brightness of 1000 cd m^{-2} . These operating voltages of devices R₅₋₈ are all lower than that of R₁₋₄, indicating the achievement of better charge injection and transport after introducing n-doping technology. The EL characteristics of R₅₋₈ are demonstrated in Fig. 6d-f. All devices show sole emission with a peak at 612 nm, demonstrating that effective energy transfer can be achieved. In the end, the n-doping based devices can obtain high EQEs over 23% and PE over 44 lm W^{-1} . Remarkably, a high performance EQE_{\max} , PE_{\max} , and CE_{\max} of 24.5%, 46.1 lm W^{-1} , and 36.0 cd A^{-1} were presented in device R₇ and it can also reach a high EQE, PE, and CE of 22.4%, 39.7 lm W^{-1} , and 22.4 cd A^{-1} at 1000 cd m^{-2} , so the 15 nm PO-T2T is effective to prevent exciton quenching. The detailed characteristics of devices R₅₋₈ are summarized in Table 2. Notably, the device efficiencies of R₇ are comparable with other reported red devices employing the same dopant (see Table S2, ESI[†]). The high EQEs and low efficiency roll-off suggest that the exciplex forming co-host using DEX has balanced charge transport and efficient utilization of excitons for radiative emission.

Conclusions

In conclusion, we fabricated an efficient green exciplex system by combining a new electron donor molecule DEX and an electron acceptor PO-T2T. Thanks to the advantages of the photophysical and electrochemical properties of DEX, the exciplex-based green OLED achieved a low operating voltage of 2.6 V at 100 cd m^{-2} as well as an excellent PE_{\max} and EQE_{\max}

of 44.1 lm W^{-1} and 11.2%. The DEX:PO-T2T exciplex as an emitter provides improved performance compared to the TCTA-based device, which is ascribed to the better carrier transport abilities and the rigid molecular structure of DEX. Furthermore, the red PhOLED employing the DEX:PO-T2T exciplex forming co-host system achieved a PE_{\max} , CE_{\max} , and EQE_{\max} of 46.1 lm W^{-1} , 36.0 cd A^{-1} , and 24.5% and low operating voltages (2.7 V at 100 cd m^{-2} and 3.4 V at 1000 cd m^{-2}). Therefore, it is believed that the proposed new electron donor DEX is beneficial to design an efficient exciplex system, which provides a reliable way to develop highly efficient OLEDs.

Experimental

Material synthesis

4,4,8,8,12,12-Hexaphenyl-8,12-dihydro-4H-benzo[9,1]quinolino[3,4,5,6,7-defg]acridine. To a solution of bromobenzene (3.52 g, 22.6 mmol) in dry diethyl ether (30 ml) was added slowly 2.4 M *n*-BuLi (11.3 mL, 27.1 mmol) at $-10\text{ }^{\circ}\text{C}$ (ice-salt bath). The obtained mixture was treated by stirring at $-10\text{ }^{\circ}\text{C}$ for 1 h, and then a solution of trimethyl 2,2',2''-nitriлотрибензоате (0.90 g, 2.15 mmol) in 20 mL dry THF was added dropwise. Then, the mixture was warmed to room temperature and stirred overnight. The reaction mixture was quenched with minimum water, and the solvent was evaporated. The crude product was treated by using boiling ethanol and filtered after cooling. The residue was cleaned with water, ethanol and hexane, and then dried under a vacuum. The dried solid was dissolved in boiling acetic acid (30 mL), and concentrated HCl (aq) (3 mL) was added dropwise. After refluxing for 3 hours, the mixture was treated with ice water (200 mL). The precipitate was obtained and washed twice with ethanol, and then purified by recrystallization from ethanol/chloroform to afford the product as white crystals (1.33 g, yield: 84%). ¹H NMR (600 MHz, CDCl₃) δ (ppm): 7.10 (t, *J* = 7.2 Hz, 6H), 7.04 (t, *J* = 7.5 Hz, 12H), 6.98 (t, *J* = 7.5 Hz, 3H), 6.85 (d, *J* = 7.8 Hz, 6H), 6.77 (d, *J* = 7.8 Hz, 12H). ¹³C NMR (CDCl₃) δ (ppm): 146.26, 135.44, 130.25, 128.58, 128.50, 127.53, 126.09, 122.54, 55.90. MS (MALDI-TOF) *m/z*: 739.30 [M⁺].

General methods

All chemicals and reagents employed in our work were obtained from commercial resources without further purification. In the synthetic routes, tetrahydrofuran (THF) and dichloromethane (CH₂Cl₂) were purified by a PURE SOLV (Innovative Technology) purification system. ¹H NMR and ¹³C NMR spectra were measured with a Bruker 600 spectrometer at room temperature. UV-vis absorption spectra were realized through a PerkinElmer Lambda 750 spectrophotometer. Photoluminescence (PL) spectra and phosphorescent spectra were measured on a Hitachi F-4600 fluorescence spectrophotometer. Differential scanning calorimetry (DSC) was performed on a TA DSC 2010 unit at a heating rate of 10 $^{\circ}\text{C min}^{-1}$ under nitrogen. Thermogravimetric analysis (TGA) was performed by using a TA SDT 2960 instrument with a heating rate of 10 $^{\circ}\text{C min}^{-1}$ under nitrogen; the temperature at 5% weight loss was used as the decomposition temperature (*T*_d).

Cyclic voltammetry was performed on a CHI600 voltammetric analyzer connected to a three-electrode system in which a platinum working electrode, a Pt wire counter electrode, and an Ag/AgCl reference electrode were employed. Ferrocenium-ferrocene (Fc^+/Fc) was used as an internal standard. Nitrogen-bubbled 0.1 mol L^{-1} tetrabutylammonium hexafluorophosphate ($[\text{Bu}_4\text{N}]\text{PF}_6$) dichloromethane solution served as a supporting electrolyte.

Device fabrication and measurement

The OLEDs were fabricated on indium tin oxide (ITO)-covered glass substrates ($15 \Omega \text{ square}^{-1}$). All substrates were ultrasonically cleaned with acetone, ethanol and deionized water for 15 min before treating with UV-ozone for 15 min. All devices were made in a thermal deposition chamber under a pressure of $4 \times 10^{-4} \text{ Pa}$. HAT-CN and Liq were deposited with a rate of 0.2 \AA s^{-1} , and 8 \AA s^{-1} for Al; other organic materials were treated with a rate of 2 \AA s^{-1} . Finally, the devices were encapsulated with glass sheets at room temperature. The electroluminescence (EL) information of all devices was measured using a PR 655 photometer connected to a constant current source (Keithley 2400 SourceMeter). Transient PL decays were obtained on a time-resolved fluorescence spectrometer (PL-TCSPC) of HORIB-FM-2015.

Conflicts of interest

The authors declare no conflict of interest.

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